TOSHIBA Photocoupler IRED + Photo IC

TLP700F

Industrial inverters
Inverter for air conditioners
IGBT/Power MOSFET gate drive

The TLP700F consists of an infrared LED and an integrated photodetector. This unit is 6-lead SDIP package. The TLP700F is 50% smaller than the 8-pin DIP and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring safety standard certification.

The TLP700F is suitable for gate driving circuits for IGBTs or power MOSFETs. In particular, the TLP700 is capable of "direct" gate driving of low-power IGBTs.

Peak output current: ±2.0 A (max)

Guaranteed performance over temperature: -40 to 100°C

• Supply current: 2.0 mA (max)

Power supply voltage:
 15 to 30 V

• Threshold input current: I_{FLH} = 5 mA (max)

• Switching time (tplh / tphl): 500 ns (max)

Common mode transient immunity: ±15 kV/µs (min)

Isolation voltage: 5000 Vrms (min)

UL-recognized: UL 1577, File No.E67349

cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349

VDE-approved: EN 60747-5-5, EN 62368-1 (Note 1)

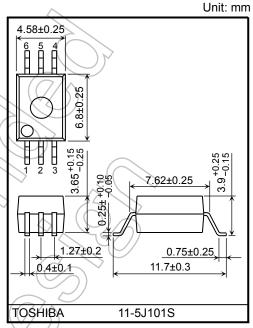
Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

Construction mechanical rating

	10.16-mm pitch TLPXXXF type
Creepage Distance Clearance Insulation Thickness	8.0 mm (min) 8.0 mm (min) 0.4 mm (min)

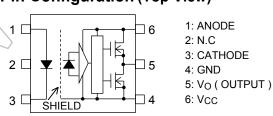
Truth Table

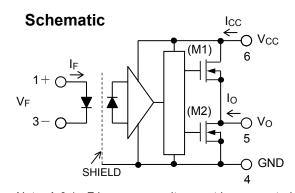
Input	LED	M1	M2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	L



Weight: 0.26 g (typ.)

Pin Configuration (Top View)





Note: A 0.1- μF bypass capacitor must be connected between pins 6 and 4.

Start of commercial production 2007-08

Absolute Maximum Ratings (Ta = 25 °C)

	Characteristics	Symbol	Rating	Unit	
	Forward current	lF	20	mA	
	Forward current derating (Ta ≥ 85°	∆l _F /∆Ta	-0.54	mA/°C	
	Peak transient forward current	IFP	1	A	
ED	Reverse voltage		V_{R}	5	V
	Diode power dissipation		P_{D}	40	mW
	Diode power dissipation derating (Ta ≥ 85 °C)	∆P _D /∆Ta	-1.0	mW/°C
	Junction temperature	Tj	125	Ç	
	"H" peak output current	Ta=-40 to 100 °C	loph	-2.0	// A))
١.	"L" peak output current	(Note 2)	IOPL	2.0	A
Detector	Output voltage		Vo	35	V
Dete	Supply voltage		Vcc	35	/ v
	Power dissipation		PC	400	mW
	Junction temperature		Tj	125	°C
Oper	rating frequency	(Note 3)	f ((50	kHz
Oper	Operating temperature range			-40 to 100	O °C
Stora	Storage temperature range			-55 to 125	°C
Lead soldering temperature (10 s) (Note 4)			Tsol	260	°C
Isola	tion voltage (AC, 60 s, R.H. ≤ 60 %) (Note 5)	BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note: A ceramic capacitor (0.1 µF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property.

The total lead length between capacitor and coupler should not exceed 1 cm.

Note 1: Pulse width Pw ≤ 1 µs, 300 pps

Note 2: Exponential waveform pulse width $P_W \le 0.3 \mu s$, $f \le 15 kHz$

Note 3: Exponential waveform $lop_H \ge -1.5 \text{ A} (\le 0.3 \text{ µs})$, $lop_L \le +1.5 \text{ A} (\le 0.3 \text{ µs})$, $Ta = 100 \, ^{\circ}\text{C}$

Note 4: For the effective lead soldering area

Note 5: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.

Recommended Operating Conditions

	/	/ >				
Characteristics		Symbol	Min	Тур.	Max	Unit
Input current, ON	(Note 1)	IF (ON)	7.5	_	10	mA
Input voltage, OFF	\wedge (VF (OFF)	0	1	0.8	٧
Supply voltage (Note 2)	(Note 3)	Vcc	15	_	30	V
Peak output current	1//	IOPH / IOPL	_	_	±1.5	Α
Operating temperature		Topr	-40	_	100	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device.

Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: Input signal rise time (fall time) \leq 0.5 μ s.

Note 2: This item denotes operating ranges, not meaning of recommended operating conditions.

Note 3: If the VCC rise slope is sharp, an internal circuit might not operate with stability. Please design the VCC rise slope under 3.0 V/µs.

Electrical Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

Characteristics		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Forward voltage		VF	_	IF = 10 mA, Ta = 25 °C	_	1.57	1.75	V
Temperature coefficient of voltage	forward	ΔV _F /ΔTa	_	I _F = 10 mA	_	-1.8	_	mV/°C
Input reverse current		IR	1	V _R = 5 V, Ta = 25 °C		_	10	μΑ
Input capacitance		Ст	-	V = 0 V, f = 1 MHz, Ta = 25 °C	(-)	100	-	pF
	"H" Level	IOPH1	1	V _{CC} = 15 V V ₆₋₅ = 3.5 V		-1.4	-1.0	
Output current	n Level	IOPH2	ı	IF = 5 mA $V_{6-5} = 7 V$	())	_	-1.5	Α
(Note 1)	"L" Level	IOPL1	2	V _{CC} = 15 V V5-4 = 2.5 V	1.0	1.4	_	A
	L Levei	I _{OPL2}	2	IF = 0 mA $V_{5-4} = 7 V$	1.5	_	_	
"H" Level		Voн	3	V _{CC1} = +15 V, V _{EE1} = -15V R _L = 200 Ω, I _F = 5 mA	11	13.7		V
Output voltage	"L" Level	V _{OL}	4	V _{CC1} = +15V, V _{EE1} = -15V R _L = 200 Ω, V _F = 0.8 V	7	-14.9	-12.5	V
Supply current	"H" Level	Іссн	5	V _{CC} = 30 V	7-7	(1.3)	2.0	mΛ
Supply current	"L" Level	ICCL	6	$V_O = Open$ $I_F = 0 mA$	7 //	1.3	2.0	mA
Threshold input current	$L \rightarrow H$	I _{FLH}	_	V _{CC} = 15 V, V _O > 1 V		1.8	5	mA
Threshold input voltage	$H \rightarrow L$	VFHL	- (Vcc = 15 V, Vo < 1 V	0.8	_	_	٧
Supply voltage		Vcc	7	_ (//)	15	_	30	٧
1000		V _{UVLO+}	4	V _O > 2.5V, I _F = 5 mA	11.0	12.5	13.5	V
UVLO thresh hold		V _U VLO-	7/	V _O < 2.5V, I _F = 5 mA	9.5	11.0	12.0	V
UVLO hysteresis		UVLO _{HYS}			_	1.5	_	V

Note: All typical values are at Ta = 25°C

Note: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design. It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

Note 1: Duration of lo time ≤ 50 µs, 1 pulse

Isolation Characteristics (Ta = 25 °C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	Vs = 0 V, f = 1 MHz	-	1.0	_	pF
Isolation resistance	Rs	R.H. ≤ 60 %, V _S = 500 V	10 ¹²	10 ¹⁴	_	Ω
Isolation voltage	BVS	AC, 60 s	5000	ı	ı	Vrms

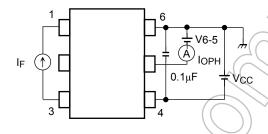
Note: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.

Switching Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

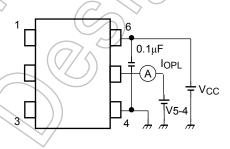
Characteristics		Symbol	Test Circuit	Test Condition		Test Condition		Min	Тур.	Max	Unit
Dranagation dalay time	$L \rightarrow H$	tрLН				$I_F = 0 \rightarrow 5 \text{ mA}$	50	_	500		
Propagation delay time	$H \rightarrow L$	tpHL		Vcc = 30 V	IF = 5 → 0 mA	50	_	500			
Output rise time (10-90 %)		tr	7		$I_F = 0 \rightarrow 5 \text{ mA}$	/	50	_	ns		
Output fall time (90-10 %)		tf			IF = 5 → 0 mA	$(-)_1$	> 50	_			
Switching time dispersion type tphL-tpLH				I _F = 0 ↔ 5 mA		_	250				
Common mode transient i at HIGH level output	mmunity	СМН	V _{CM} = 1000 Vp-p		I _F = 5 mA V _{O (min)} = 26 V	-15	_	_	k) //uo		
Common mode transient i at LOW level output	mmunity	CML	0	Ta = 25 °C V _{CC} = 30 V	I _F = 0 mA V _O (max) = 1 V	15	_	_	kV/μs		

Note: All typical values are at Ta = 25 °C.

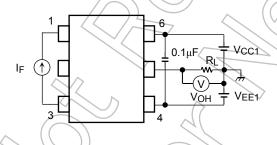




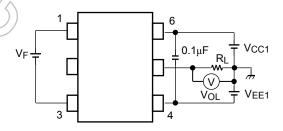
Test Circuit 2: IOPL



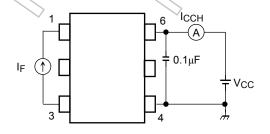
Test Circuit 3: VOH



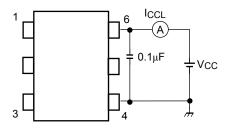
Test Circuit 4: Vol



Test Circuit 5: ICCH

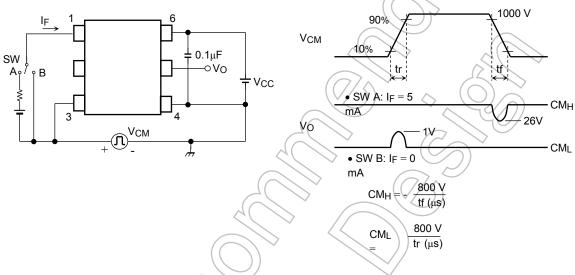


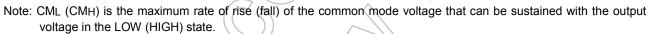
Test Circuit 6: ICCL



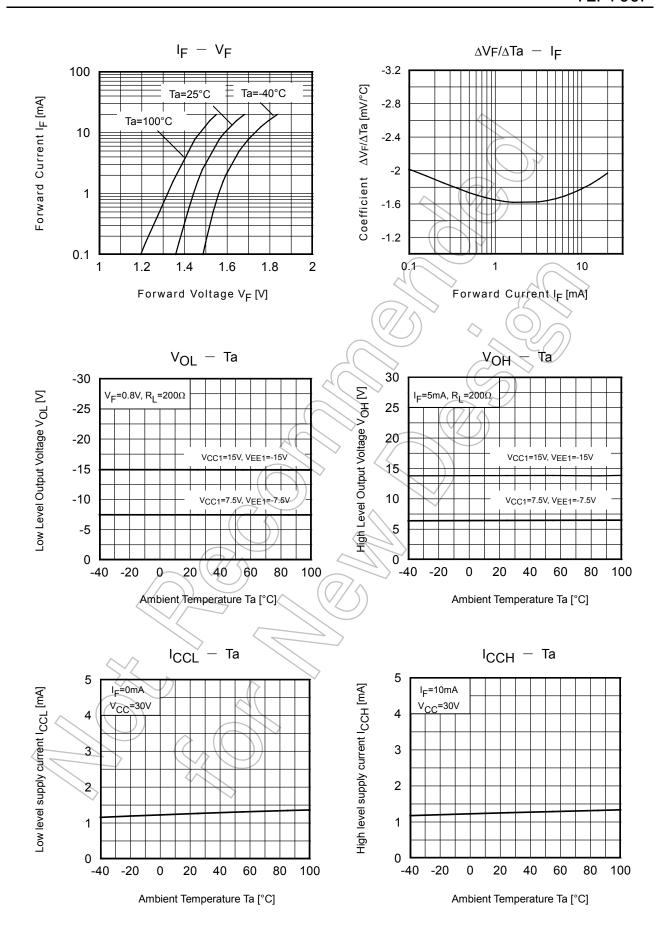
Test Circuit 7: tpLH, tpHL, tr, tf, | tpHL-tpLH |

(f=25kHz, duty=50%, less than tr=tf=5ns) ____ IF ◇-Vон tf Cg = 10nF V_{CC} $Rg = 20 \Omega$ 90% 50% 10% tpHL tpLH Vol Test Circuit 8: CMH, CML 1000 V 90%

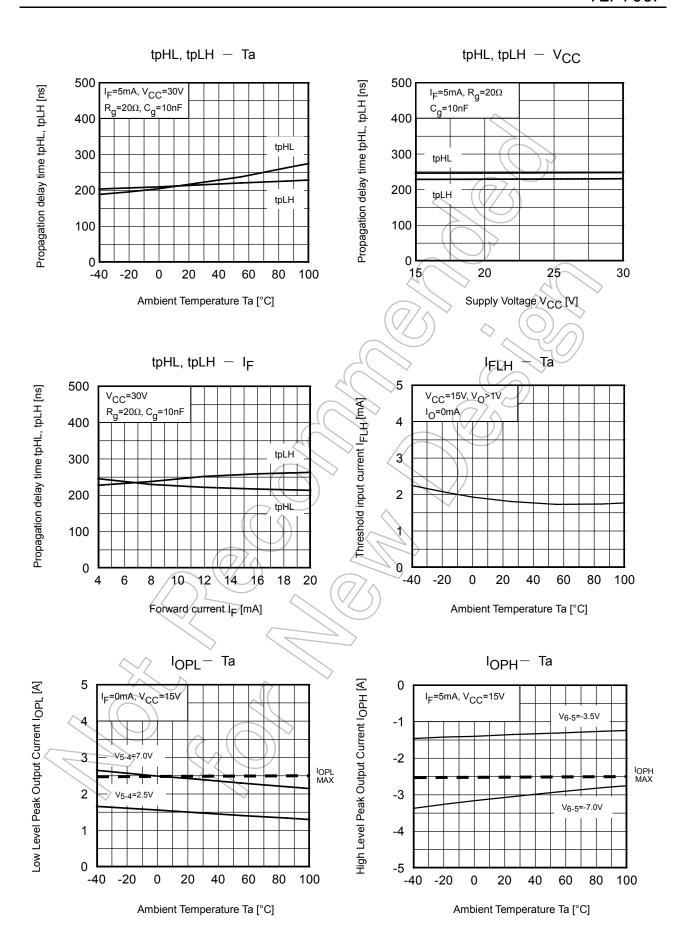




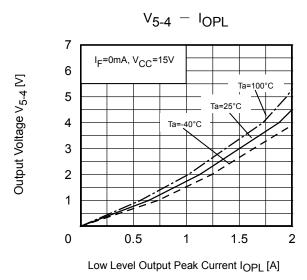


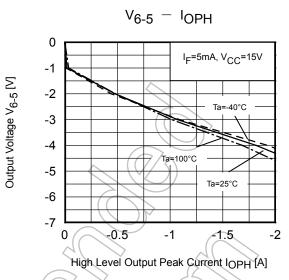


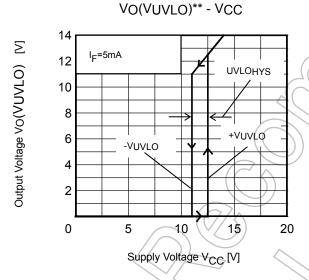
NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

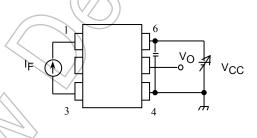


NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.









**Test Circuit : VO(VUVLO) - VCC

*: The above graphs show typical characteristics.

NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Soldering and Storage

(1) Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

1) When Using Soldering Reflow

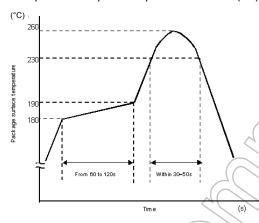
The soldering temperature profile is based on the package surface temperature.

(See the figure shown below, which is based on the package surface temperature.)

Reflow soldering must be performed once or twice.

The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

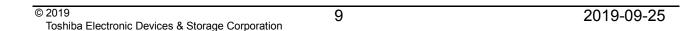
An example of a temperature profile when lead(Pb)-free solder is used:



This profile is based on the device's maximum heat resistance guaranteed value.

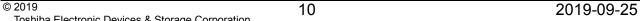
Set the preheat temperature/heating temperature to the optimum temperature corresponding to the solder paste type used by the customer within the described profile.

- 2) When using soldering Flow
 - Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.
 - Mounting condition of 260 °C or less within 10 seconds is recommended.
 - Flow soldering must be performed once
- 3) When using soldering Iron (Applicable to both eutectic solder and Lead(Pb)-Free solder)
 - Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C.
 - Heating by soldering iron must be only once per 1 lead



(2) Precautions for General Storage

- 1) Do not store devices at any place where they will be exposed to moisture or direct sunlight.
- 2) When transportation or storage of devices, follow the cautions indicated on the carton box.
- 3) The storage area temperature should be kept within a temperature range of 5 °C to 35 °C, and relative humidity should be maintained at between 45% and 75%.
- 4) Do not store devices in the presence of harmful (especially corrosive) gases, or in dusty conditions.
- 5) Use storage areas where there is minimal temperature fluctuation. Because rapid temperature changes can cause condensation to occur on stored devices, resulting in lead oxidation or corrosion, as a result, the solderability of the leads will be degraded.
- 6) When repacking devices, use anti-static containers.
- 7) Do not apply any external force or load directly to devices while they are in storage.
- 8) If devices have been stored for more than two years, even though the above conditions have been followed, it is recommended that solderability of them should be tested before they are used.



EN 60747-5-5 Option (D4) Specification

Types : TLP700F

Type designations for "option: (D4)", which are tested under EN 60747 requirements.

Ex.: TLP700F (D4-TP,F) D4 : EN 60747 option

TP: Standard tape & reel type

F: [[G]]/RoHS COMPATIBLE (Note 1)

Note: Use TOSHIBA standard type number for safety standard application.

Ex.: TLP700F (D4-TP,F) → TLP700F

Note 1: Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

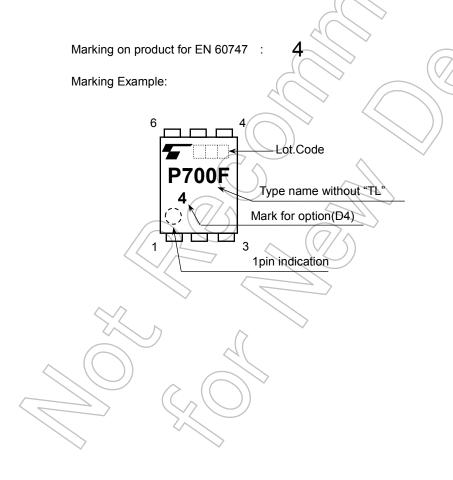
EN 60747 Isolation Characteristics

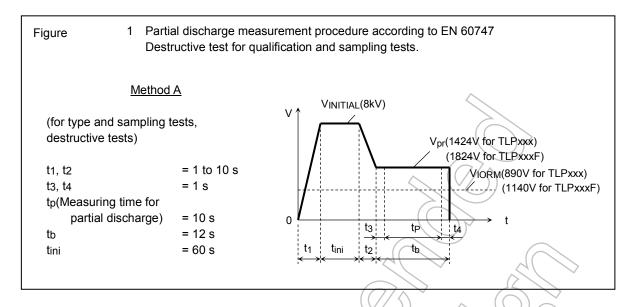
Description		Symbol	Rating	Unit	
Application classification					
for rated mains voltage ≤ 300V _{rms} for rated mains voltage ≤ 600V _{rms}		I-IV I-III	_		
Climatic classification			40/ 100 / 21	_	
Pollution degree			2	_	
Maximum aparating insulation valtage	TLPxxx type	.,	890) (ml	
Maximum operating insulation voltage	TLPxxxFtype	V _{IORM}	1140	Vpk	
Input to output test voltage, method A	TLPxxx type		1424	Vpk	
Vpr=1.6 × V _{IORM} , type and sample test tp=10 s, partial discharge<5 pC	TLPxxxFtype	Vpr	1824		
Input to output test voltage, method B	TLPxxx type		1670		
Vpr=1.875 × Viorm, 100 % production test t _p =1 s, partial discharge < 5 pC	TLPxxxFtype	Vpr	2140	Vpk	
Highest permissible overvoltage (transient overvoltage, t _{pr} = 60/s)		V _{TR}	8000	Vpk	
Safety limiting values (max. permissible ratings in case of fault, also refer to thermal derat					
current (input current I _F , P _{si} = 0)	Isi	300	mA		
power (output or total power dissipation)	Psi	700	mW		
temperature		Ts	150	°C	
Insulation resistance, $V_{IO} = 500 \text{ V}$, $Ta = 25 ^{\circ}\text{C}$			≥10 ¹²		
V _{IO} =500 V, Ta = 100 °C	,	Rsi	≥10 ¹¹	Ω	
V _{IO} =500 V, Ta = Ts			≥10 ⁹		

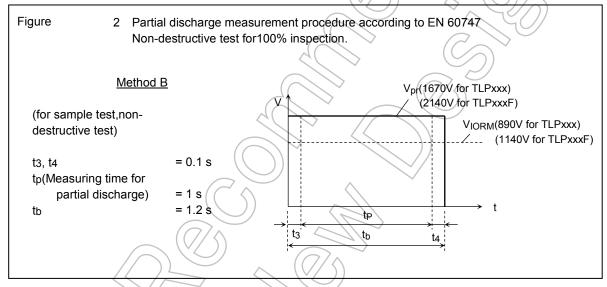
Insulation Related Specifications

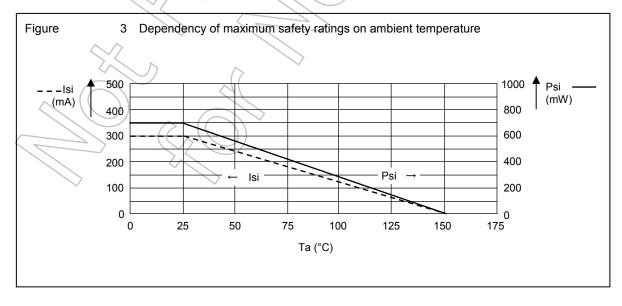
		7.62mm pitch TLPxxx type	10.16mm pitch TLPxxxF type
Minimum creepage distance	Cr	7.0mm	8.0mm
Minimum clearance	CI	7.0mm	8.0mm
Minimum insulation thickness	ti	0,4m	im
Comperative tracking index	СТІ	17:	5

- 1. If a printed circuit is incorporated, the creepage distance and clearance may be reduced below this value. If this is not permissible, the user shall take suitable measures.
- 2. This photocoupler is suitable for 'safe electrical isolation' only within the safety limit data. Maintenance of the safety data shall be ensured by means of protective circuits.









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